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June 2014

FDMA430NZ

Single N-Channel 2.5V Specified PowerTrench[®] MOSFET

30V, 5.0A, 40mΩ

General Description

This Single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench process to optimize the $R_{DS(on)}$ @ $V_{GS}=2.5V$ on special MicroFET leadframe.

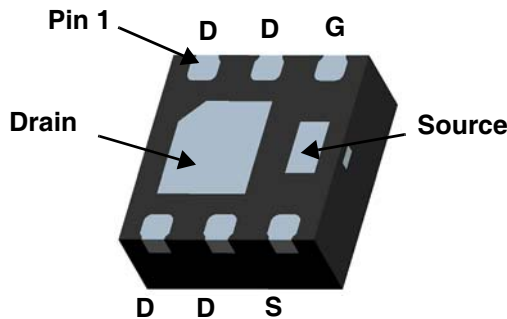
Applications

- Li-Ion Battery Pack

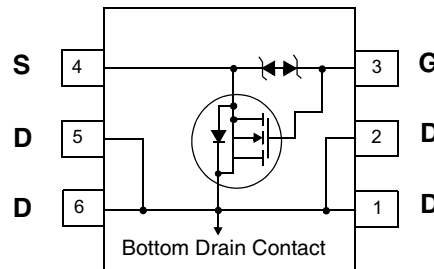


Features

- $R_{DS(on)} = 40m\Omega$ @ $V_{GS} = 4.5 V, I_D = 5.0A$
- $R_{DS(on)} = 50m\Omega$ @ $V_{GS} = 2.5 V, I_D = 4.5A$
- Low Profile-0.8mm maximum-in the new package MicroFET 2x2 mm
- HBM ESD protection level > 2.5kV typical (Note 3)
- Free from halogenated compounds and antimony oxides
- RoHS Compliant



MicroFET 2X2 (Bottom View)



Absolute Maximum Ratings $T_A = 25^\circ C$ unless otherwise noted

| Symbol | Parameter | Rated | Units |
|----------------|---|-------------|------------|
| V_{DSS} | Drain-Source Voltage | 30 | V |
| V_{GSS} | Gate-Source Voltage | ± 12 | V |
| I_D | Drain Current -Continuous (Note 1a) -Pulsed | 5.0 | A |
| | | 20 | |
| P_D | Power dissipation (Steady State) (Note 1a) (Note 1b) | 2.4 | W |
| | | 0.9 | |
| T_J, T_{STG} | Operating and Storage Junction Temperature Range | -55 to +150 | $^\circ C$ |

Thermal Characteristics

| | | | |
|-----------------|---|-----|--------------|
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient (Note 1a) | 52 | $^\circ C/W$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient (Note 1b) | 145 | |

Package Marking and Ordering Information

| Device Marking | Device | Reel Size | Tape Width | Quantity |
|----------------|-----------|-----------|------------|------------|
| 430 | FDMA430NZ | 7" | 8 mm | 3000 units |

FDMA430NZ Single N-Channel 2.5V Specified PowerTrench[®] MOSFET

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Units |
|--------|-----------|-----------------|-----|-----|-----|-------|
|--------|-----------|-----------------|-----|-----|-----|-------|

Off Characteristics

| | | | | | | |
|--------------------------------------|---|--|----|------|----------|----------------------|
| B_{VDSS} | Drain-Source Breakdown Voltage | $V_{GS} = 0V, I_D = 250\mu A$ | 30 | | | V |
| $\frac{\Delta B_{VDSS}}{\Delta T_J}$ | Breakdown Voltage Temperature Coefficient | $I_D = 250\mu A$, Referenced to 25°C | | 25.2 | | mV/ $^\circ\text{C}$ |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = 24V, V_{GS} = 0V$, | | | 1 | μA |
| I_{GSS} | Gate-Body Leakage, | $V_{GS} = \pm 12V, V_{DS} = 0V$ | | | ± 10 | μA |

On Characteristics (Note 2)

| | | | | | | |
|--|--|--|-----|------|-----|----------------------|
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250\mu A$ | 0.6 | 0.81 | 1.5 | V |
| $\frac{\Delta V_{GS(th)}}{\Delta T_J}$ | Gate Threshold Voltage Temperature Coefficient | $I_D = 250\mu A$, Referenced to 25°C | | -3.2 | | mV/ $^\circ\text{C}$ |
| $R_{DS(on)}$ | Static Drain-Source On-Resistance | $V_{GS} = 4.5V, I_D = 5.0A$ | | 23.6 | 40 | m Ω |
| | | $V_{GS} = 4.0V, I_D = 5.0A$ | | 23.9 | 41 | |
| | | $V_{GS} = 3.1V, I_D = 4.5A$ | | 25.4 | 43 | |
| | | $V_{GS} = 2.5V, I_D = 4.5A$ | | 27.6 | 50 | |
| | | $V_{GS} = 4.5V, I_D = 5.0A$, $T_J = 150^\circ\text{C}$ | | 37.0 | 61 | |
| g_{FS} | Forward Transconductance | $V_{DS} = 5V, I_D = 5.0A$ | | 25.6 | | S |

Dynamic Characteristics

| | | | | | | |
|-----------|------------------------------|--|--|-----|-----|----------|
| C_{iss} | Input Capacitance | $V_{DS} = 10V, V_{GS} = 0V$, $f = 1.0\text{MHz}$ | | 600 | 800 | pF |
| C_{oss} | Output Capacitance | | | 110 | 150 | pF |
| C_{rss} | Reverse Transfer Capacitance | | | 75 | 115 | pF |
| R_G | Gate Resistance | $f = 1.0\text{MHz}$ | | 3.5 | | Ω |

Switching Characteristics (Note 2)

| | | | | | | |
|--------------|---------------------|--|--|------|----|----|
| $t_{d(on)}$ | Turn-On Delay Time | $V_{DD} = 10V, I_D = 1A$ $V_{GS} = 4.5V, R_{GEN} = 6\Omega$ | | 8.3 | 17 | ns |
| t_r | Turn-On Rise Time | | | 7.1 | 15 | ns |
| $t_{d(off)}$ | Turn-Off Delay Time | | | 18.1 | 37 | ns |
| t_f | Turn-Off Fall Time | | | 6.0 | 12 | ns |
| Q_g | Total Gate Charge | $V_{DS} = 10V, I_D = 5.0A$, $V_{GS} = 4.5V$ | | 7.3 | 11 | nC |
| Q_{gs} | Gate-Source Charge | | | 0.8 | 2 | nC |
| Q_{gd} | Gate-Drain Charge | | | 1.9 | 3 | nC |

Drain-Source Diode Characteristics and Maximum Ratings

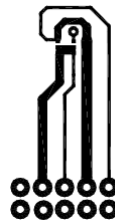
| | | | | | |
|----------|---|---------------------------|------|-----|----|
| I_S | Maximum Continuous Drain-Source Diode Forward Current | | | 2.0 | A |
| V_{SD} | Drain-Source Diode Forward Voltage | $V_{GS} = 0V, I_S = 2.0A$ | 0.69 | 1.2 | V |
| t_{rr} | Diode Reverse Recovery Time | $I_F = 5.0A$, | | 17 | ns |
| Q_{rr} | Diode Reverse Recovery Charge | $di/dt = 100A/\mu s$ | | 5 | nC |

Notes:

1. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.



a. 52 $^\circ\text{C/W}$ when mounted on a 1 in² pad of 2 oz copper.



b. 145 $^\circ\text{C/W}$ when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%

3. The diode connected between the gate and the source serves only as protection against ESD. No gate overvoltage rating is implied.

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

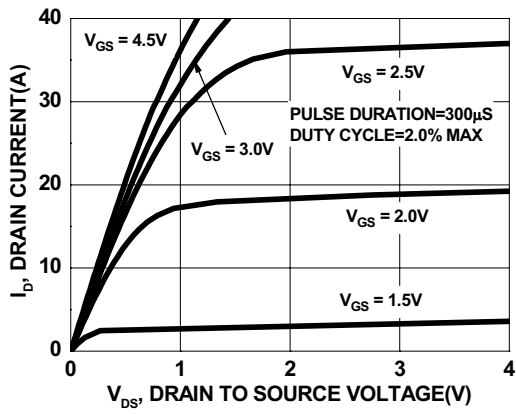


Figure 1. On Region Characteristics

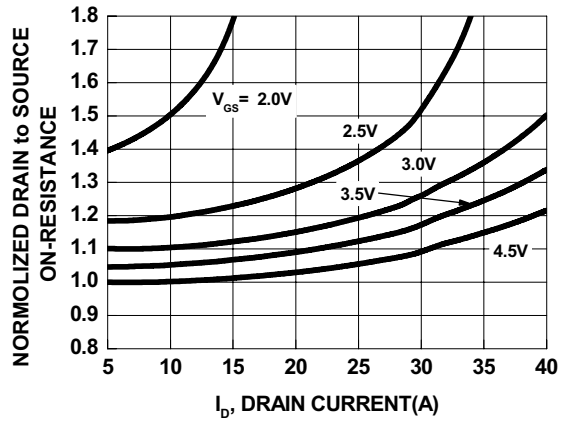


Figure 2. On-Resistance vs Drain Current and Gate Voltage

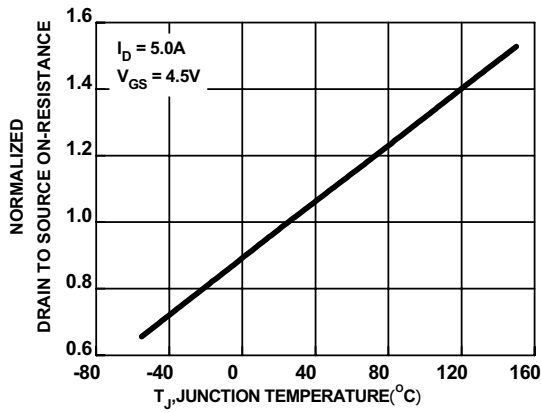


Figure 3. Normalized On Resistance vs Junction Temperature

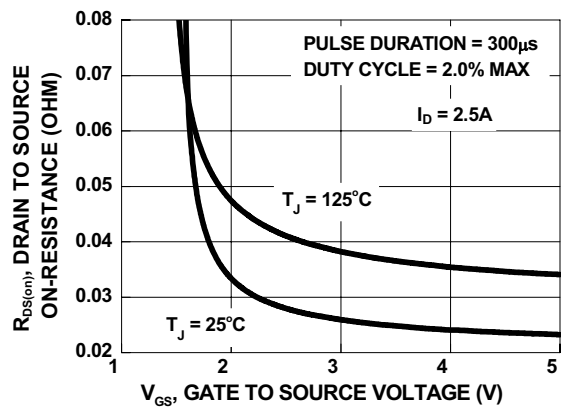


Figure 4. On-Resistance vs Gate to Source Voltage

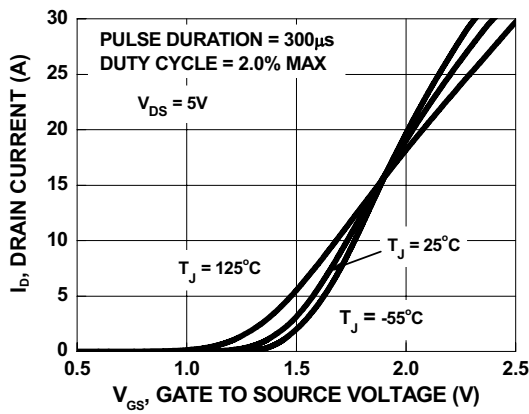


Figure 5. Transfer Characteristics

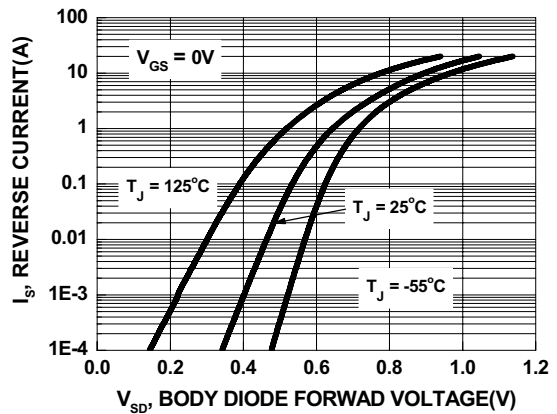


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

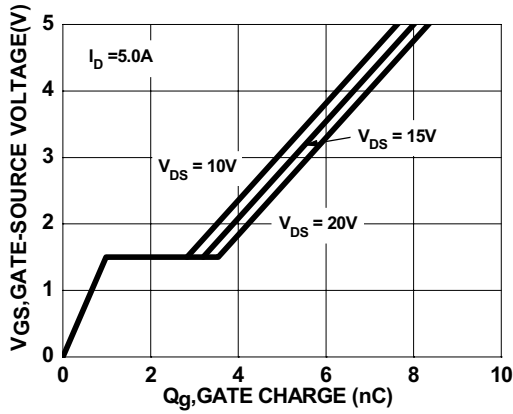


Figure 7. Gate Charge Characteristics

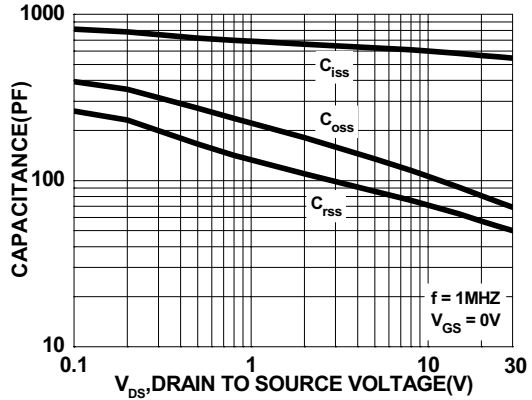


Figure 8. Capacitance vs Drain to Source Voltage

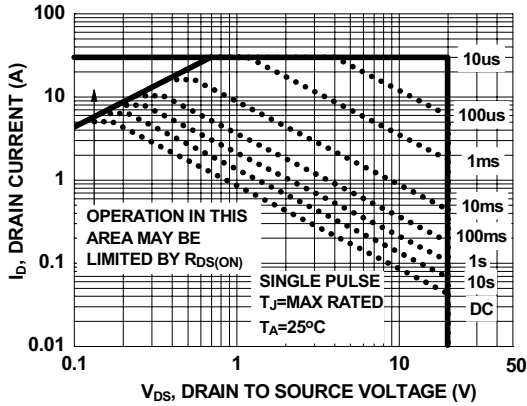


Figure 9. Safe Operating Area

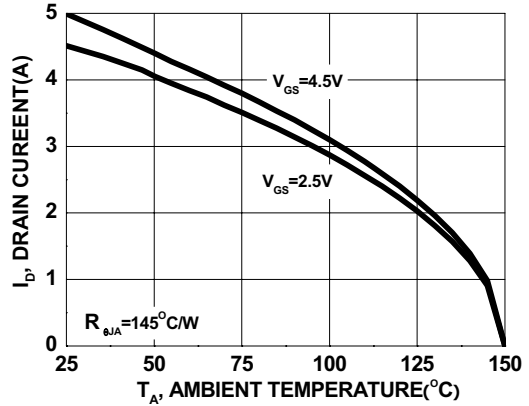


Figure 10. Maximum Continuous Drain Current vs Ambient Temperature

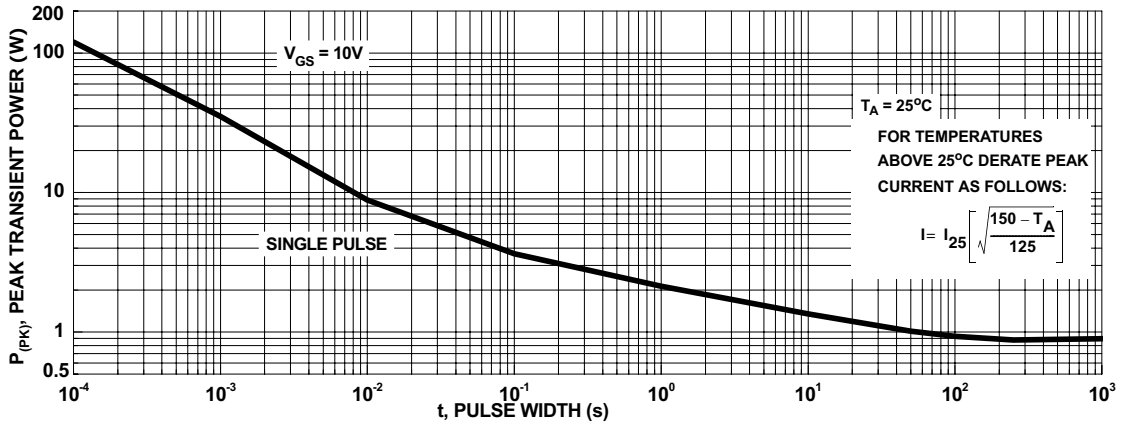


Figure 11. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

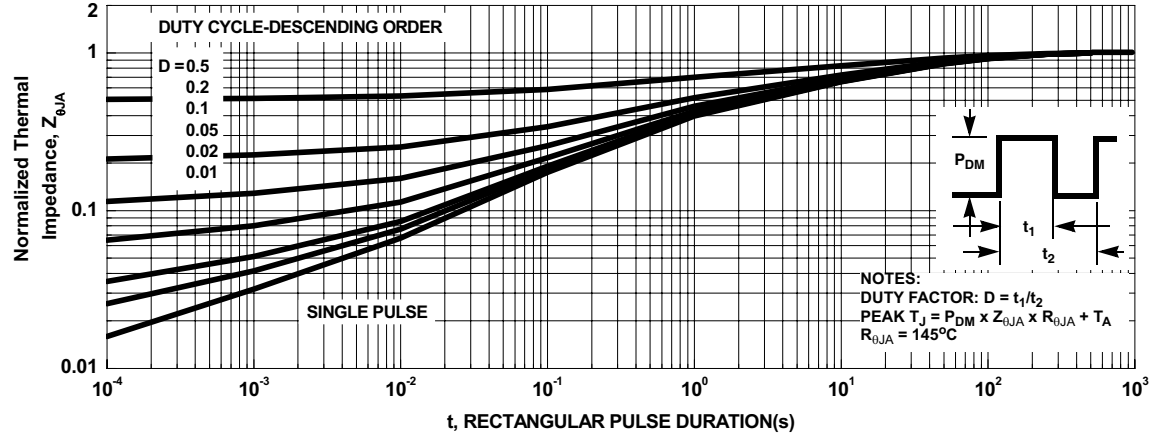
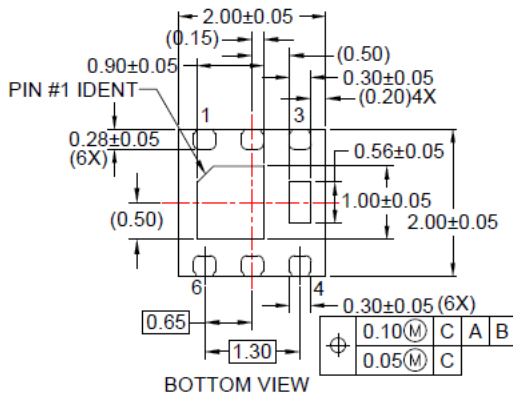
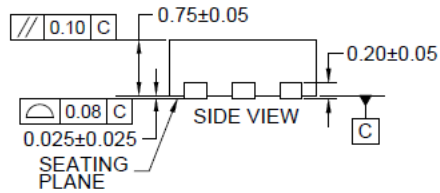
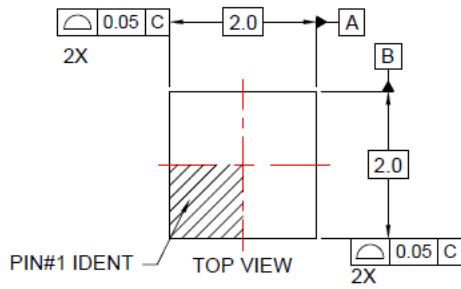


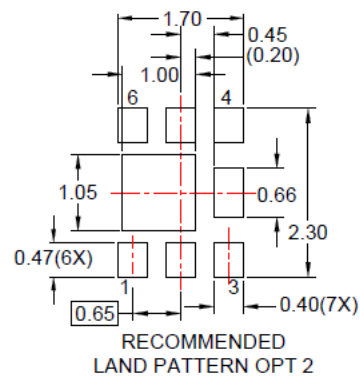
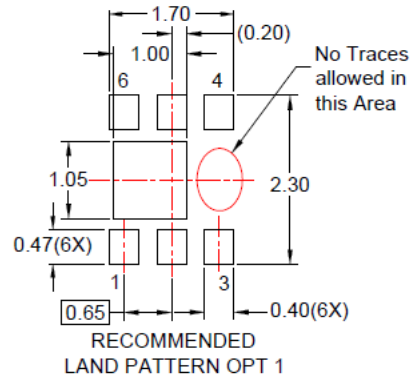
Figure 12. Transient Thermal Response Curve

Dimensional Outline and Pad Layout



NOTES:

- A. PACKAGE DOES NOT FULLY CONFORM TO JEDEC MO-229 REGISTRATION
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
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